## MA3X157A (MA157A)

## Silicon epitaxial planar type

For switching circuits

## Features

- High switching speed
- Small terminal capacitance $\mathrm{C}_{\mathrm{t}}$
- Both chips have even characteristics

Absolute Maximum Ratings $\mathrm{T}_{\mathrm{a}}=25^{\circ} \mathrm{C}$

| Parameter |  | Symbol | Rating | Unit |
| :---: | :---: | :---: | :---: | :---: |
| Reverse voltage |  | $\mathrm{V}_{\mathrm{R}}$ | 80 | V |
| Maximum peak reverse voltage |  | $\mathrm{V}_{\mathrm{RM}}$ | 80 | V |
| Forward current | Single | $\mathrm{IF}_{\mathrm{F}}$ | 100 | mA |
|  | Series |  | 65 |  |
| Peak forward current | Single | $\mathrm{I}_{\mathrm{FM}}$ | 225 | mA |
|  | Series |  | 145 |  |
| Non-repetitive peak forward surge current* | Single | $\mathrm{I}_{\text {FSM }}$ | 500 | mA |
|  | Series |  | 325 |  |
| Junction temperature |  | $\mathrm{T}_{\mathrm{j}}$ | 150 | ${ }^{\circ} \mathrm{C}$ |
| Storage temperature |  | $\mathrm{T}_{\text {stg }}$ | -55 to +150 | ${ }^{\circ} \mathrm{C}$ |

Note) *: $\mathrm{t}=1 \mathrm{~s}$


Marking Symbol: MS
Internal Connection


Electrical Characteristics $\mathrm{T}_{\mathrm{a}}=25^{\circ} \mathrm{C} \pm 3^{\circ} \mathrm{C}$

| Parameter | Symbol | Conditions | Min | Typ | Max | Unit |
| :--- | :---: | :--- | :---: | :---: | :---: | :---: |
| Forward voltage | $\mathrm{V}_{\mathrm{F}}$ | $\mathrm{I}_{\mathrm{F}}=100 \mathrm{~mA}$ |  |  | 1.2 | V |
| Reverse voltage | $\mathrm{V}_{\mathrm{R}}$ | $\mathrm{I}_{\mathrm{R}}=100 \mu \mathrm{~A}$ | 80 |  |  | V |
| Reverse current | $\mathrm{I}_{\mathrm{R}}$ | $\mathrm{V}_{\mathrm{R}}=75 \mathrm{~V}$ |  |  | 100 | nA |
| Terminal capacitance | $\mathrm{C}_{\mathrm{t}}$ | $\mathrm{V}_{\mathrm{R}}=0 \mathrm{~V}, \mathrm{f}=1 \mathrm{MHz}$ |  |  | 2 | pF |
| Reverse recovery time * | $\mathrm{t}_{\mathrm{rr}}$ | $\mathrm{I}_{\mathrm{F}}=10 \mathrm{~mA}, \mathrm{~V}_{\mathrm{R}}=6 \mathrm{~V}$ <br> $\mathrm{I}_{\mathrm{rr}}=0.1 \mathrm{I}_{\mathrm{R}}, \mathrm{R}_{\mathrm{L}}=100 \Omega$ |  |  | 3 | ns |

Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7031 measuring methods for diodes.
2. Absolute frequency of input and output is 100 MHz .
3. $*: \mathrm{t}_{\mathrm{rr}}$ measurement circuit


Note) The part number in the parenthesis shows conventional part number.


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